Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0,	("memoryadjcellanddriverandrailandw ordadjlineandbitadjlineandpitch").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/22 12:29
L2	148	memory adj cell and driver and rail and word adj line and bit adj line and pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 12:32
L3	82	memory adj cell and driver and rail and word adj line and bit adj line and pitch and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:43
L4	2	("6593624").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/22 12:47
L5	1	"6841813".pn. and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 12:48

L6	140	("20010055838	"   "2002	0028541"	US-PGPUB;	OR	ON	2006/01/22 12:48
		"3414892"   "3 <sub>4</sub>	•	·	USPAT;			
		"3573757"   "3!	576549" Ì	"3582908"	USOCR			
		"3629863"   "36	634929"	"3671948"				
		"3699543"   "3	717852"	"3728695"				
		"3787822"   "38		•				
		"3877049"   "38		•				
		"3980505"   "39		•				•
		"4177475"   "4		•				
		"4272880"   "42						
		"4420766"   "4		•				•
		"4494135"   "4		•				
		"4500905"   "4!		•				
		"4543594"   "4!						
i		"4646266"   "46		•				
		"4710798"   "47		•				
		"4811114"   "48		•				
		"4876220"   "48   "4922319"   "49		•				
		"5070383"   "50						
		"5091762"   "5		•				
		"5202754"   "52		•				
		"5306935"   "5:		•				
		"5383149"   "5:		•				
		"5398200"   "5 <sub>4</sub>		•				
		"5427979"   "5 <sub>4</sub>		•				
		"5453952"   "54		•				
		"5468997"   "54		•				
		"5495398"   "5!		•				
		"5523628"   "5!		•				
Ì		"5552963"   "5!	561622"	"5572046"				
ļ		"5581498"   "5	585675"	"5654220"				
		"5675547"   "50	693552"	"5696031"				
		"5703747"   "5	737259"	"5745407"				
		"5751012"   "57		•				
			801437"	"5835396"				
		"5883409"   "59						
		"5969380"   "59						
		"5981974"   "59		•				
		"6057598"   "60						
		"6107666"   "6:						
		"6133640"   "6:	185122").	PN. OR				
		("6197641"   "6						
İ		"6291858"   "63						
		"6322903"   "63						
		"6353265"   "63						
		"6653733"   "R		.PN. UK				
		("6841813").UR						
L7	1	"6593624".pn. a	and drive	r	US-PGPUB;	OR	ON	2006/01/22 12:49
		-			USPAT;			
					EPO; JPO;			
					DERWENT			
L8	38	matrix.as. and	device ad	i level	US-PGPUB;	OR	ON	2006/01/22 12:50
	50	maanias, ana t	SCTICE GG	,	USPAT;	<b>.</b>		
					EPO; JPO;			•
					DERWENT			

L9	15	memory adj cell and driver and rail and word adj line and bit adj line and substrate and device adj level	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 13:20
L10	0	"5060045".pn. and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 14:33
L11	1	"5060045".pn. and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:07
L12	37	memory adj cell and driver near5 substrate and rail and word adj line and bit adj line and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 13:20
L13	1	"6631085".pn. and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:06
L14	1	"6631085".pn. and driver same substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:02
L15	1	"5060045".pn. and photolithography	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 14:52
L16	0	"6631085".pn. and dummy	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:39
L17	0	"5060045".pn. and dummy	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:14
L18	22	memory adj cell and driver and rail and word adj line and bit adj line and pitch and substrate and dummy	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:07
L19	2	"6486066".pn. and dummy	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:29
L20	2	"20050121790".pn. and interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 17:08

L21	15	memory adj cell and driver and rail and word adj line and bit adj line and vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:33
L22	1	"6631085".pn. and bit adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:23
L23	1	"20050121790".pn. and (segment or global) near5 bit	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:43
L24	11	memory adj cell and driver and rail and word adj line and global near5 bit adj line and segment near5 bit adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:44
L25	89	global near5 bit adj line and segment near5 bit adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:56
L26	18	word adj line near5 word near3 driver near5 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 15:56
L27	1	"6631085".pn. and passive	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:16
L28	2	"6631085".pn. and (anti adj fuse or antifuse)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:21
L29	1	"6631085".pn. and ("tft" or thin adj film) and charge	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:23
L30	o	"6631085".pn. and nand	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:24
L31	1	memory adj cell near5 ("tft" or thin adj film adj transistor) near5 charge adj storage near5 dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:25
L32	15	memory adj cell same ("tft" or thin adj film adj transistor) same charge adj storage same dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:41

L33	51	memory adj cell near5 series near5 nand adj string	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:27
L34	1	memory adj line same vertical adj interconnect same interleaved	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:51
L35	0	memory adj line near5 connect near5 vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:51
L36	2	memory adj line near5 vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:51
L37	2	memory adj line same vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:44
L38	0	memory adj line near5 connect near5 interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:44
L39	0	memory near5 connect near5 vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:46
L40	30	memory near5 vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:46
L41	0	rail near5 connect near5 vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:51
L42	1	rail same vertical adj interconnect same interleaved	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:51
L43	5	rail near5 vertical adj interconnect	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22.16:53
L44	1	rail same zias	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:54

L45	1000	rail and (zias or vertical interconnect) and memory adj cell	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:55
L46	86	rail and (zias or vertical adj interconnect) and memory adj cell	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:55
L47	1	rail and (zias or vertical adj interconnect) and memory adj cell and memory adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 16:55
L48	1	"20050121790".pn. and substrate adj device and driver and fan adj out and rail	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 17:21
L49	1	"20050121790".pn. and nand	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 17:52
L50	545	257/206.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 17:52
S1	75	matrix.as. and pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/22 12:49
S2	9	matrix.as. and substrate near5 pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/11 18:44
S3	2	("6373553").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/11 18:44
S4	7	("4828392"   "4972075"   "5703675"). PN. OR ("6373553").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/11 18:44
S5	37	("5242770"   "5256505"   "5340700"   "5447810"   "5636002"   "5707765"   "5723233"   "5821014"   "5827623"   "5849440"   "5922513"   "5958635"   "6013397"   "6077310"   "6081658"   "6120953"   "6165693"   "6265121"   "6284419"   "6291112"   "6303252"   "6312856"   "6319644"   "6335130"   "6338922"   "6373553"   "6413683"   "6421820"   "6453457"   "6459156"   "6472108"   "6482559"   "6485891"   "6519760"   "6620564"   "6795163"   "6871337").PN. OR ("6964032").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/11 18:46

			<del></del>	<del> </del>		<del></del>
S6	6	("6094305").PN. OR ("6519760"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/11 18:46
S7	2	("6373553").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/12 13:05
S8	2	("5652084").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/12 13:05
S9	19	("4548688"   "4775609"   "4814243"   "4826756"   "4859573"   "4904866"   "4908656"   "4931351"   "4985374"   "5158910"   "5219787"   "5270236"   "5300403"   "5319247"   "5320932"   "5352630").PN. OR ("5652084").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/12 13:10
S10	32	cleeves.in. and pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 13:19
S11	2	"5652084".pn. and pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 15:48
S12	2	("5677712").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/12 13:21
S13	2	("5686223").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/12 14:26
S14	505	257/758.ccls. and pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 14:30
S15	34	257/758.ccls. and pitch and memory and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 15:52
S16	2	("5990507"   "6018195").PN. OR ("6057573").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/12 14:35
S17	8	("5060045"   "5631478"   "5633479"   "5834845").PN. OR ("6483176").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/12 14:38
S18	32	("5060045"   "5119170").PN. OR ("5631478").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/12 14:39

S19	21	("4424621"   "4513310"   "4543443"   "4612083"   "4630094"   "4725566"   "4733291"   "4788582"   "4962410"   "4994868").PN. OR ("5119170").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/12 14:41
S20	1	"6057573".pn. and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 15:13
S21	1	"6351406".pn. and pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 15:50
S22	1	"6351406".pn. and driver	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 15:50
S23	2206	CMOS and pitch and memory and driver and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 15:55
S24	2	("6034436").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/12 15:53
S25	1015	CMOS and pitch and memory adj cell and driver and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 18:19
S26	2	"5869858".pn. and floating adj gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 18:21
S27	1	"5869858".pn. and buried	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/01/12 18:28
S28	2	("5932908").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/01/12 18:28